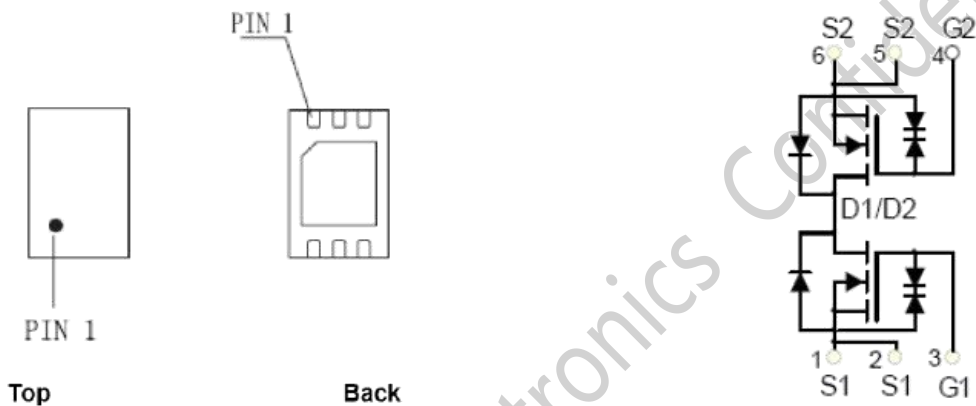


GENERAL DESCRIPTION

DP8207 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

PRODUCT SUMMARY

V_{DS}	20 V
I_D (at $V_{GS}=4.5V$)	7A
$R_{DS(ON)}$ (at $V_{GS} = 4.5V$)	13m Ω
$R_{DS(ON)}$ (at $V_{GS} = 3.8V$)	15m Ω
$R_{DS(ON)}$ (at $V_{GS} = 2.5V$)	17m Ω

ESD Protected

ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	± 10	V
Continuous Drain Current ^c	I_D	7	A
Pulsed Drain Current ^{a,c}	I_{DM}	42	A
Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 150	$^\circ C$
Lead Temperature for Soldering Purposes(1/8" from case for 10 s)	TL	260	$^\circ C$

THERMAL CHARACTERISTIC

Parameter		Symbol	Limit	Unit
Maximum Junction-to-Ambient	Steady-State	$R_{\theta JA}$	83	$^{\circ}\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

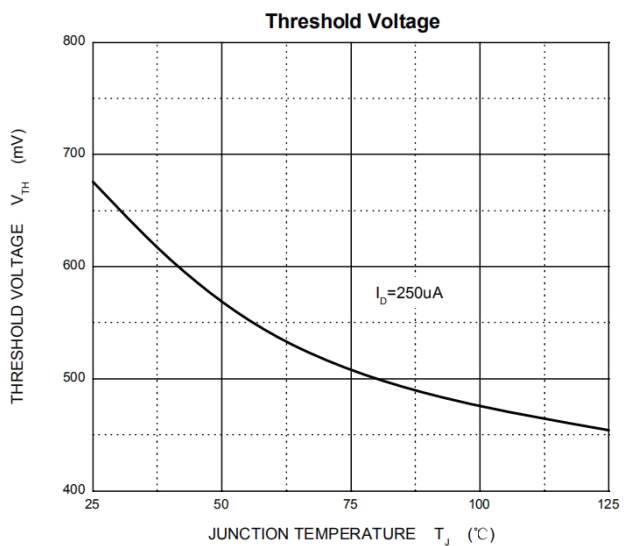
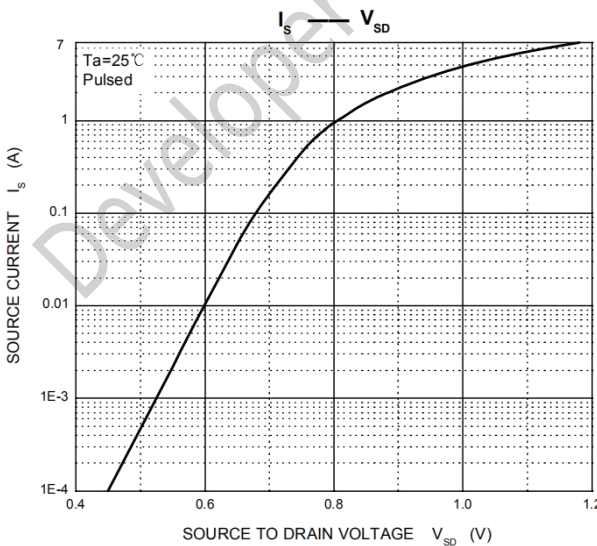
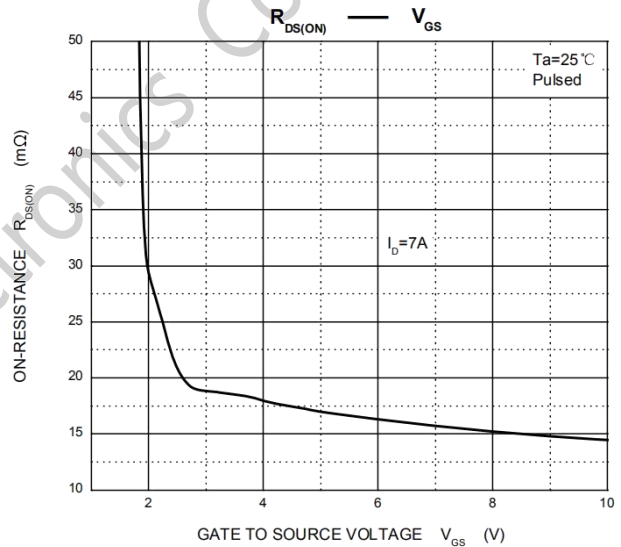
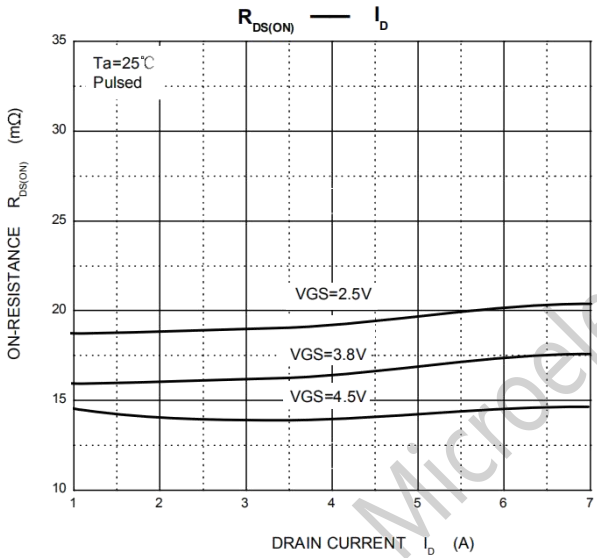
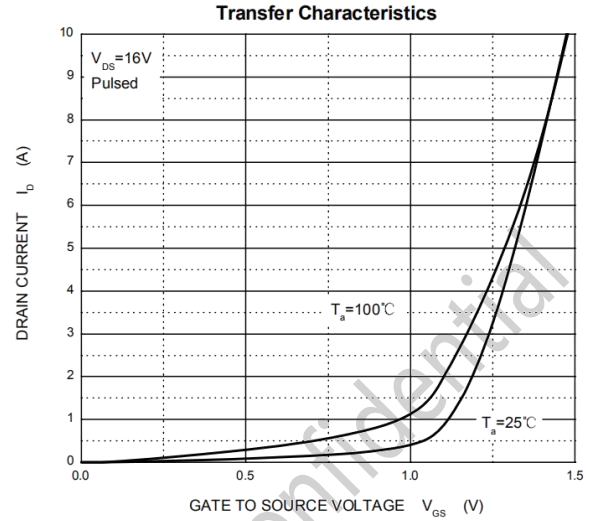
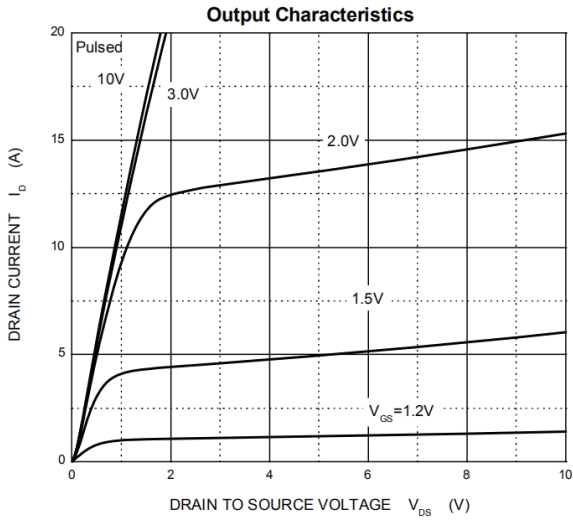
Parameter	Symbol	Condition	Min	Typc	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	20	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=20V, V_{GS}=0V$	-	-	1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS}=\pm 10V, V_{DS}=0V$	-	-	± 10	μA
On Characteristics						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.5	-	0.9	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=6.5A$	11	13	18	m Ω
		$V_{GS}=3.8V, I_D=5.5A$	13	15	20	m Ω
		$V_{GS}=2.5V, I_D=5.5A$	14	17	24	m Ω
Forward Transconductance	g_{FS}	$V_{DS}=5V, I_D=7A$	9	-	-	S
Dynamic Characteristics ^b						
Input Capacitance	C_{iss}	$V_{DS}=10V,$ $V_{GS}=0V,$ $F=1.0\text{MHz}$	-	1150	-	pF
Output Capacitance	C_{oss}		-	185	-	pF
Reverse Transfer Capacitance	C_{rss}		-	145	-	pF
Switching Characteristics ^b						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=10V,$ $V_{GS}=5V,$ $R_L=1.35\Omega,$ $R_{GEN}=3\Omega,$	-	6	-	nS
Turn-on Rise Time	t_r		-	13	-	nS
Turn-Off Delay Time	$t_{d(off)}$		-	52	-	nS
Turn-Off Fall Time	t_f		-	16	-	nS
Total Gate Charge	Q_g	$V_{DS}=10V,$ $I_D=4.5A,$ $V_{GS}=7V$	-	15	-	nC
Gate-Source Charge	Q_{gs}		-	0.8	-	nC
Gate-Drain Charge	Q_{gd}		-	3.2	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=1A$	-	-	1	V
Maximum Body-Diode	I_S	-	-	-	6.0	A

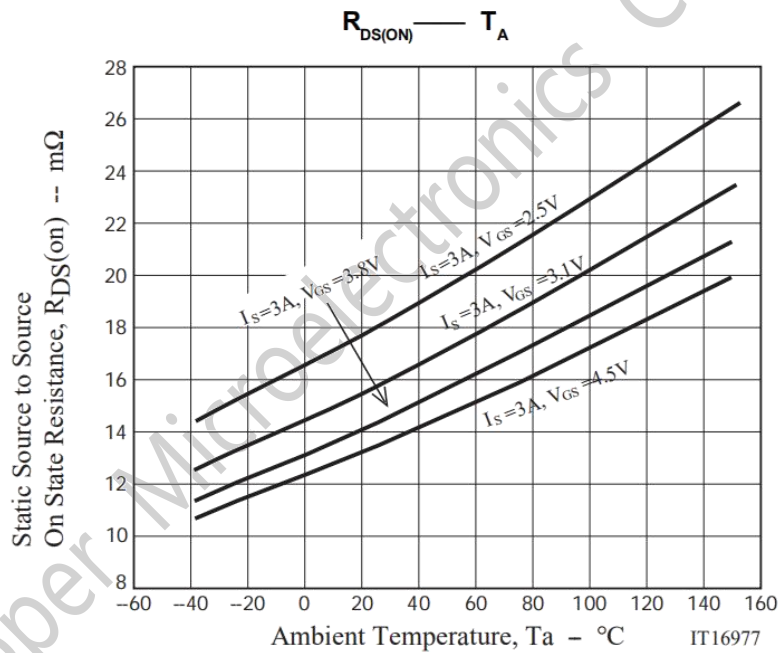
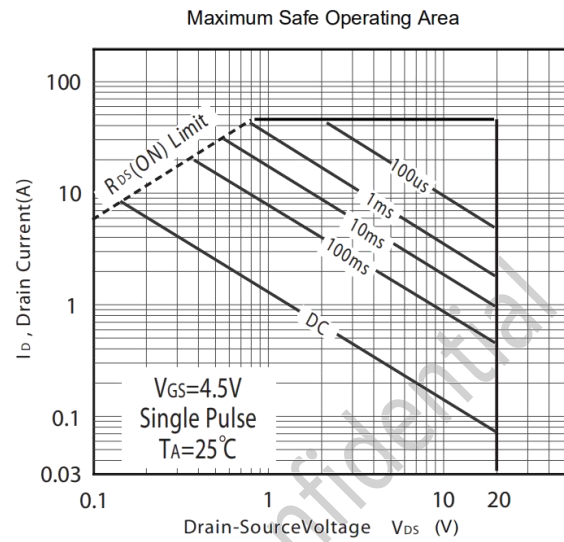
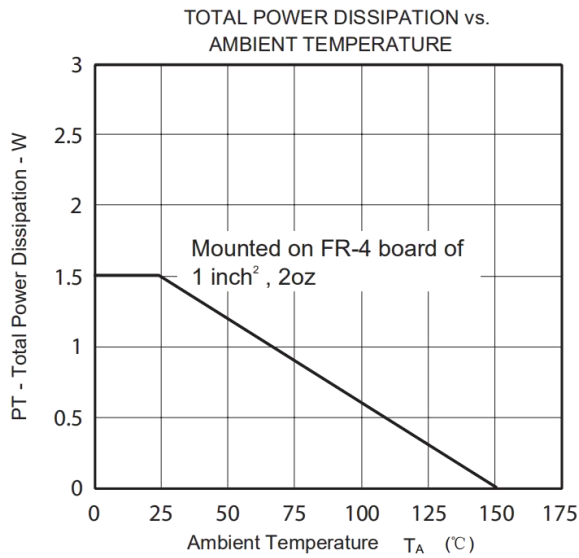
Notes

a.Pulse Test:Pulse Width < 300us, Duty Cycle < 0.5%.

b.Guaranteed by design, not subject to production testing.

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS





MARKING DESCRIPTION

TDFN2X3-6L

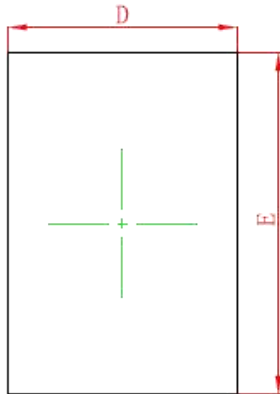
**NOTE:**

- Y —Code of productive year code(the last number of the year)
M —Code of productive month(for example: A means January, B means February...)
DD —Productive date(the number of the date)
NN —Lot number of wafer

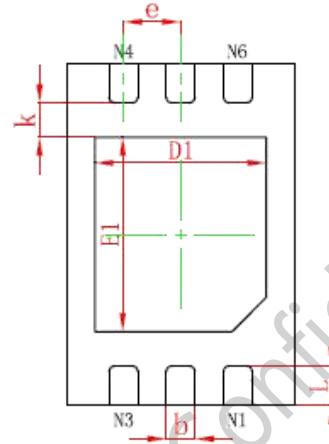
FOR EXCAMPLE:

5G1103

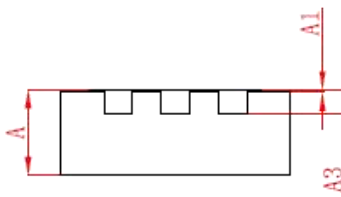
Means this product was produced in 2015-07-11 ,
and 03 is the wafer lot.

PACKAGE OUTLINE DIMENSIONS
TDFN2X3-6L


TOP VIEW

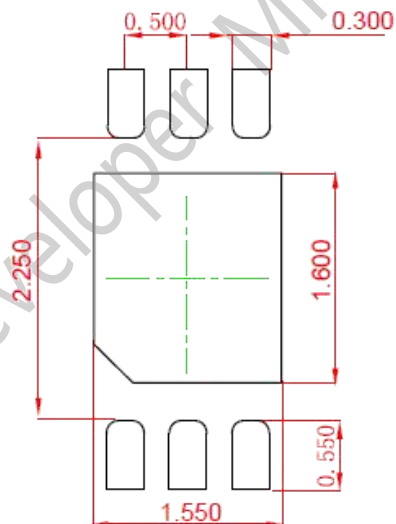


BOTTOM VIEW



SIDE VIEW

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A3	0.203REF.		0.008REF.	
D	1.950	2.050	0.077	0.081
E	2.950	3.050	0.116	0.120
D1	1.450	1.550	0.057	0.061
E1	1.650	1.750	0.065	0.069
k	0.200MIN.		0.008MIN.	
b	0.200	0.300	0.008	0.012
e	0.500TYP.		0.020TYP.	
L	0.300	0.400	0.012	0.016


Note:

1. Controlling dimension: In millimeters.
2. General tolerance: ± 0.050 mm.
3. The pad layout is for reference purposes only.

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